SPN1308 N-Channel Enhancement Mode MOSFET

DESCRIPTION

The SPN1308 is the N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

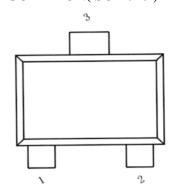
APPLICATIONS

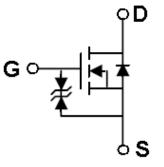
- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

FEATURES

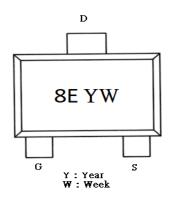
- N-Channel 30V/1.4A,RDS(ON)= $122m\Omega@VGS=10V$ 30V/1.0A,RDS(ON)= $134m\Omega@VGS=4.5V$ 30V/0.5A,RDS(ON)= $175m\Omega@VGS=2.5V$
- ◆ Super high density cell design for extremely low RDS(ON)
- Exceptional on-resistance and maximum DC current capability
- ♦ ESD protected
- ♦ SOT-323 package design

PIN CONFIGURATION(SOT-323)





PART MARKING



PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN1308S32RGB	SOT-323	8E

[※] SPN1308S32RGB : Tape Reel ; Pb − Free ; Halogen − Free ; 3K/Reel

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit
Drain-Source Voltage		Vdss	30	V
Gate –Source Voltage		VGSS	±12	V
Continuous Drain Current(T _J =150°C)	Ta=25°C	ID	1.4	A
Pulsed Drain Current		IDM	6	A
Continuous Source Current(Diode Conduction)		Is	0.3	A
Power Dissipation	Ta=25°C	PD	0.33	W
Operating Junction Temperature		TJ	-55/150	°C
Storage Temperature Range		Tstg	-55/150	°C
Thermal Resistance-Junction to Ambient		RθJA	100	°C/W

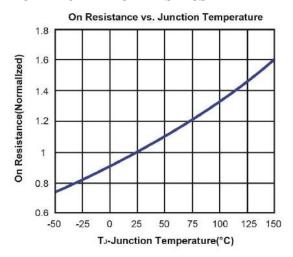
ELECTRICAL CHARACTERISTICS

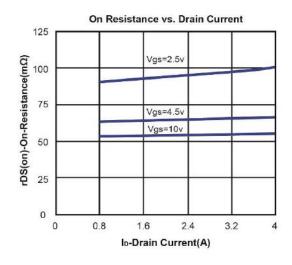
(TA=25°C Unless otherwise noted)

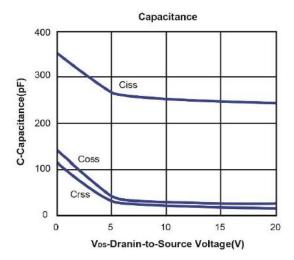
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V(BR)DSS	Vgs=0V,ID= 250uA	30			V	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.6		1.5] v	
Gate Leakage Current	Igss	$V_{DS}=0V,V_{GS}=\pm 10V$			±10	uA	
		VDS= 24V,VGS=0V			1		
Zero Gate Voltage Drain Current	Idss	V_{DS} = 24V, V_{GS} =0V T_{J} =55 $^{\circ}$ C			10	uA	
Drain-Source On-Resistance		Vgs=10V,Id=1.4A		100	122	mΩ	
	RDS(on)	VGS=4.5V,ID=1A		110 132	134 175		
Diode Forward Voltage	VsD	V _{GS} =2.5V,I _D =0.5A I _S =1.4A,V _{GS} =0V		132	1.2	V	
Dynamic							
Total Gate Charge	Qg	VDS=15V,VGS=4.5V,		4.5		nC	
Gate-Source Charge	Qgs	ID=1.4A		1.4			
Gate-Drain Charge	Qgd			1.3			
Input Capacitance	Ciss			249		pF	
Output Capacitance	Coss	V _{DS} =15V _{GS} =0V f=1MHz		27			
Reverse Transfer Capacitance	Crss	-1-11VII1Z		20			
Turn-On Time	td(on)	V 15VD- 440		10.4		nS	
	tr	-VDD=15V,RL=4.4 Ω , ID=1.4A		47.5			
Turn-Off Time	td(off)	$V_{GEN}=10V,R_{G}=6\Omega$		70.1			
	tf	1		62.3			

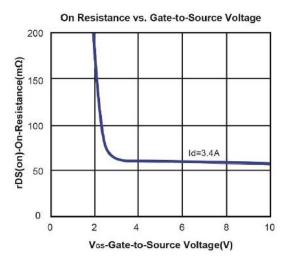


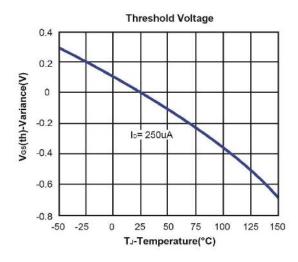
TYPICAL CHARACTERISTICS

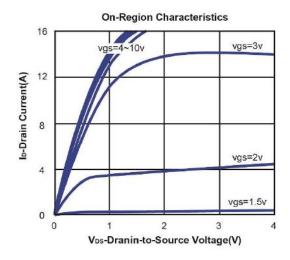




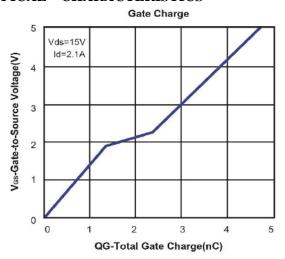


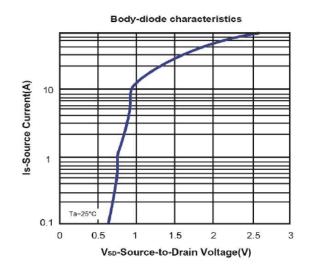


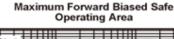


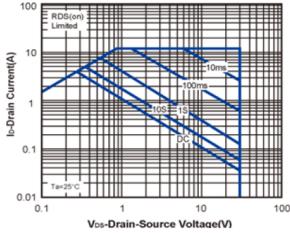


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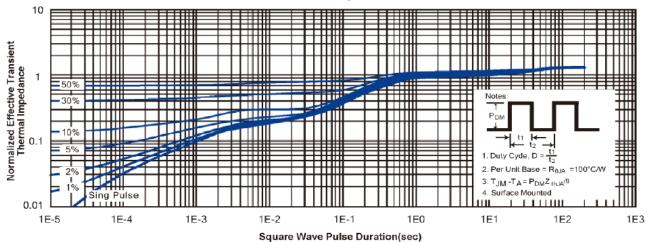












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SYNC Power Corporation
7F-2, No.3-1, Park Street
NanKang District (NKSP), Taipei, Taiwan 115
Phone: 886-2-2655-8178

Fax: 886-2-2655-8468 © http://www.syncpower.com